

#### **DESCRIPTION**

The IS281 series optocoupler consists of an infrared emitting diode optically coupled to an NPN silicon photo transistor.

This device belongs to Isocom Compact Range of Optocouplers.

#### **FEATURES**

- Half Pitch 1.27mm
- High AC Isolation voltage 3750V<sub>RMS</sub>
- CTR Selections Available
- Wide Operating Temperature Range -55°C to 110°C
- Pb Free and RoHS Compliant
- UL Approval E91231, Model "THP"

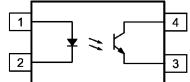
#### **APPLICATIONS**

- Switching Mode Power Supply
- Industrial System Controllers
- Measuring Instruments
- Signal Transmission between Systems of Different Potentials and Impedances

#### ORDER INFORMATION

Available in Tape and Reel with 1000pcs per reel





- Anode
- 2 Cathode
- Emitter
- Collector

#### ABSOLUTE MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

Stresses exceeding the absolute maximum ratings can cause permanent damage to the device.

Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.

#### Input

Forward Current	50mA
Reverse Voltage	6V
Power dissipation	70mW

### Output

Collector to Emitter Voltage BV <sub>CEO</sub>	80V
Emitter to Collector Voltage BV <sub>ECO</sub>	7V
Collector Current	50mA
Power Dissipation	150mW

#### Total Package

Isolation Voltage	$3750V_{RMS}$
Total Power Dissipation	200mW
Operating Temperature	-55 to 110 °C
Storage Temperature	-55 to 150 °C
Lead Soldering Temperature	260°C
(10s)	

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# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise specified)

## **INPUT**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward Voltage	$V_{\mathrm{F}}$	$I_F = 20 \text{mA}$		1.2	1.4	V
Reverse Current	$I_R$	$V_R = 4V$			10	μΑ
Terminal Capacitance	$C_{IN}$	V = 0V, $f = 1KHz$		30	250	pF

## **OUTPUT**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector-Emitter Breakdown Voltage	$\mathrm{BV}_{\mathrm{CEO}}$	$I_C = 0.1 \text{mA}, I_F = 0 \text{ mA}$	80			V
Emitter-Collector Breakdown Voltage	$\mathrm{BV}_{\mathrm{ECO}}$	$I_E = 0.1 \text{mA}, I_F = 0 \text{mA}$	7			V
Collector-Emitter Dark Current	$I_{CEO}$	$V_{CE} = 20V$ , $I_F = 0mA$			100	nA



# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise specified)

### **COUPLED**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	CTR	$I_F = 5mA$ , $V_{CE} = 5V$				%
		IS281	50		600	
		IS281A	80		160	
		IS281B	130		260	
		IS281C	200		400	
		IS281D	300		600	
		IS281E	100		200	
		IS281F	150		300	
		IS281GB	100		600	
		$I_F = 10 \text{mA}, V_{CE} = 5 \text{V}$				
		IS281H	40		80	
		IS281I	63		125	
		IS281J	100		200	
		IS281K	160		320	
		IS281GR	100		300	
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	$I_F = 10 \text{mA}, I_C = 1 \text{mA}$		0.1	0.2	V
Floating Capacitance	$C_{\mathrm{f}}$	$V_F = 0V$ , $f = 1MHz$		0.3		pF
Output Rise Time	t <sub>r</sub>	$V_{CE} = 2V$ , $Ic = 2mA$ , $R_L = 100\Omega$		6	18	μs
Output Fall Time	$t_{\mathrm{f}}$	$V_{CE} = 2V$ , $Ic = 2mA$ , $R_L = 100\Omega$		6	18	μs

### **ISOLATION**

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Isolation Voltage	$V_{\rm ISO}$	R.H. = 40% to 60%, t = 1 min Note 1	3750			$V_{RMS}$
Input - Output Resistance	R <sub>I-O</sub>	$V_{I-O} = 500 VDC$ R.H. = 40% to 60% Note 1	5x10 <sup>10</sup>			Ω

Note 1: Measured with input leads shorted together and output leads shorted together.



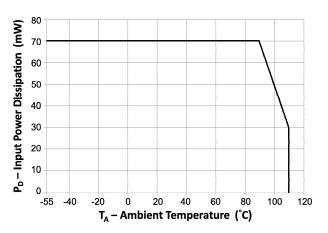


Fig 1 Input Power Dissipation vs Ambient Temperature

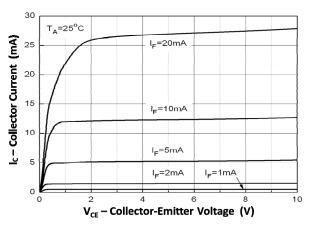


Fig 3 Collector Current vs Collector-Emitter Voltage (1)

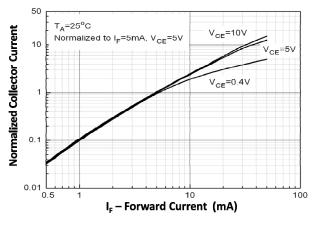


Fig 5 Normalized Collector Current vs Forward Voltage

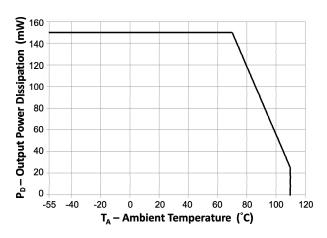


Fig 2 Output Power Dissipation vs Ambient Temperature

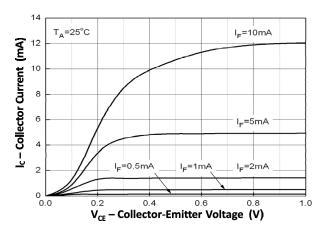


Fig 4 Collector Current vs Collector-Emitter Voltage (2)

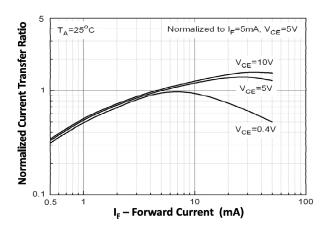


Fig 6 Collector Current Transfer Ratio vs Forward Current



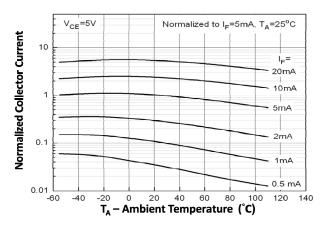


Fig 7 Normalized Collector Current vs Ambient Temperature

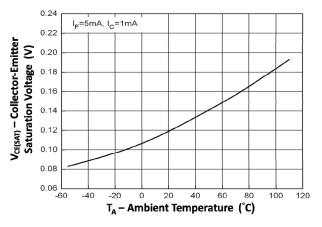


Fig 9 Collector-Emitter Voltage vs Ambient Temperature

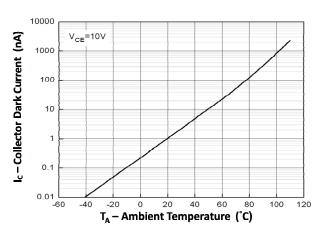


Fig 11 Collector Dark Current vs Ambient Temperature

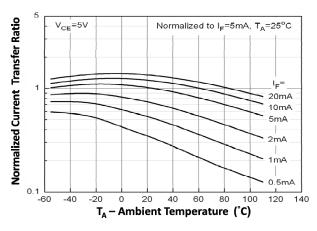


Fig 8 Normalized Current Transfer Ratio vs Ambient Temperature

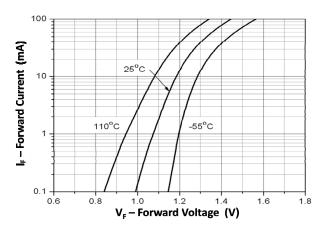


Fig 10 Forward Current vs Forward Voltage



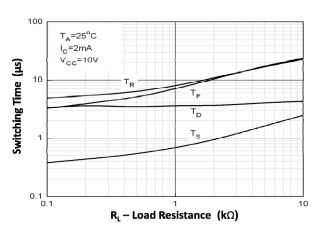
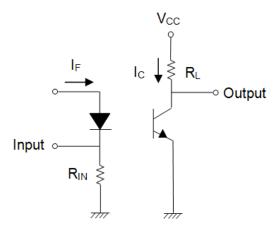
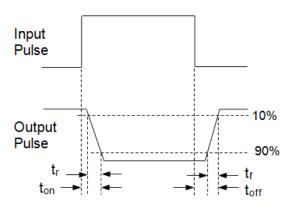


Fig 12 Switching Time vs Load Resistance





**Switching Time Test Circuit** 



#### **ORDER INFORMATION**

	IS281					
After PN	PN	Description	Packing quantity			
None	IS281	Surface Mount Tape & Reel	1000 pcs per reel			
Any CTR Grade	IS281A, IS281B, IS281C, IS281D, IS281E, IS281F, IS281H, IS281I, IS281J, IS281K, IS281GR, IS281GB	Surface Mount Tape & Reel	1000 pcs per reel			

NOTE: Multiple Grades may be supplied to meet the requested specification

#### **DEVICE MARKING**



THP\_ denotes Device Part Number where "\_" denotes CTR Grade

I denotes Isocom

Y denotes 1 digit Year code

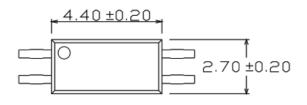
WW denotes 2 digit Week code

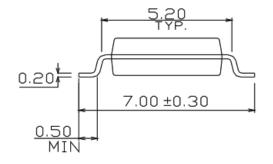
Note: Device Optional Marking

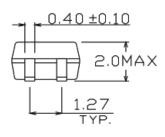
IS281 THP1
IS281B THP3
IS281F THP10



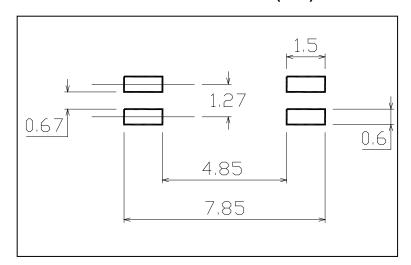
# **PACKAGE DIMENSIONS (mm)**





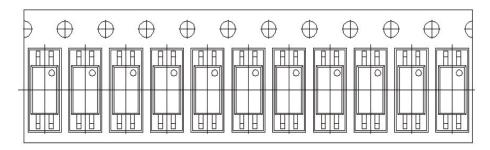


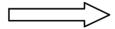
## **RECOMMENDED SOLDER PAD LAYOUT (mm)**



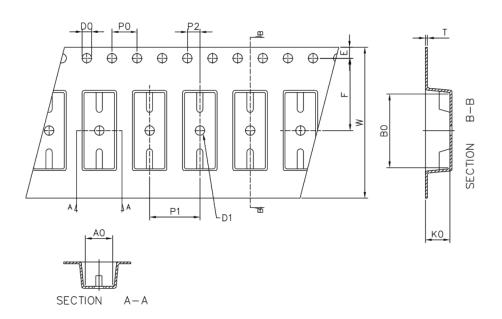


# **Tape and Reel Packaging**





# Direction of feed from reel

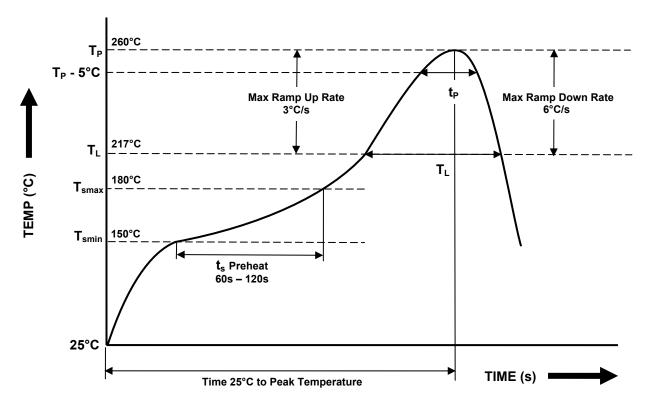


Dimension No.	Α0	В0	D0	D1	E	F
Dimension( mm)	3.00±0.10	7.45±0.10	1.50+0.1/-0	1.50±0.10	1.75±0.10	5.5±0.10
Dimension No.	P0	P1	P2	t	w	K0
Dimension (mm)	4.00±0.15	4.00±0.10	2.00±0.10	0.30±0.05	12.1±0.2	2.45±0.1



### IR REFLOW SOLDERING TEMPERATURE PROFILE

One Time Reflow Soldering is Recommended. Do not immerse device body in solder paste.



Profile Details	Conditions
$ \begin{array}{l} \textbf{Preheat} \\ \textbf{- Min Temperature } (T_{SMIN}) \\ \textbf{- Max Temperature } (T_{SMAX}) \\ \textbf{- Time } T_{SMIN} \text{ to } T_{SMAX} \left(t_s\right) \end{array} $	150°C 180°C 60s - 120s
	260°C 217°C 20s 60s 3°C/s max 3 - 6°C/s
Average Ramp Up Rate (T <sub>smax</sub> to T <sub>P</sub> )	3°C/s max
Time 25°C to Peak Temperature	8 minutes max



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